## MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

**PLED** 

# Broduct data sheet



#### **Features**

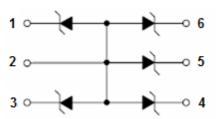
- Small SOT-363 SMT Package
- Peak Power Dissipation 100W @8 x 20 us Pulse
- Low Leakage Current < 1uA @3 Volts</li>
- Fast Response Time < 1 ns
- Low Capacitance
- ESD Protection to IEC 61000-4-2 Level 4
- RoHS Compliant in Lead-Free Versions

## SOT363



#### **Applications**

- Instrumentation Equipement
- Serial and Parallel Ports
- Microprocessor Based Equipment
- Notebooks, Desktops, Servers



#### **Electrical Characteristics** Ratings at 25°C ambient temperature unless otherwise specified.

D/N	Mandrina	V <sub>RWM</sub>	$V_{BR}$	lτ	V <sub>c</sub> @1A	Vc		С	I <sub>R</sub> μΑ (Max)	C (Pf) (Typ.)
P/N	Marking	(V)	(V)	(mA)		(Max)	(@A)			
SMF05C	5C	5	6	1	9.8	15.5	6.5	1	55	

#### **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ррр	100	W
ESD per IEC 61000-4-2 (Air)	\/	±15	Ku
ESD per IEC 61000-4-2 (Contact)	- Vesd	±8	Kv
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$
Storage Temperature Range	Тѕтл	-55 to +150	$^{\circ}$ C



Fig1.  $8/20\mu s$  Pulse Waveform

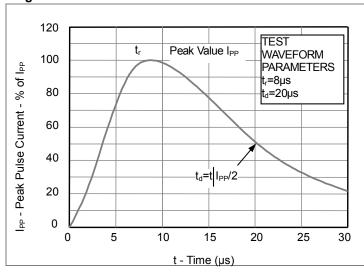


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

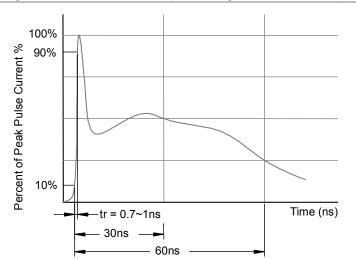
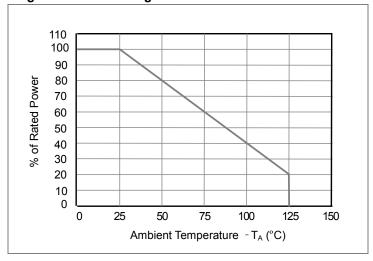
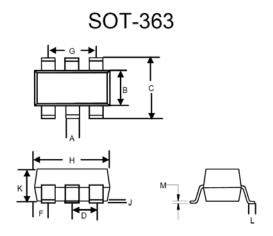


Fig3. Power Derating Curve





## **Package Dimensions**



DIMENSIONS					
	INCHES		М		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.004	.012	0.10	0.30	
В	.045	.053	1.15	1.35	
С	.079	.087	2.00	2.20	
D	.026		0.65Nominal		
F	.012	.016	0.30	0.40	
Н	.071	.087	1.80	2.20	
J		.004		0.10	
K	.035	.039	0.90	1.00	
L	.010	.016	0.25	0.40	
М	.004	.016	0.10	0.25	

#### **REEL SPECIFICATION**

P/N	PKG	QTY
SMF05C	SOT-363	3000



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